Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) in IITO220 internally insulated plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ($T_{\text{i(max)}} = 150 \,^{\circ}\text{C}$).

2. Features and benefits

- High junction operating temperature capability (T_{i(max)} = 150 °C)
- · High bidirectional blocking voltage capability
- · Very high current surge capability
- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- Internally insulated package
- · Isolated mounting base with 2500 V (RMS) isolation

3. Applications

- · Protection circuit in Power Supplies for Consumer / Industrial / Medical Equipment
- Capacitive Discharge Ignition (CDI)
- · Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit			
Absolute maximum rating							
V_{DRM}	repetitive peak off-state voltage		600	V			
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 116 °C; Fig. 1; Fig. 2; Fig. 3	20	А			
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	230	А			
		half sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 8.3 ms$	253	А			
T _j	junction temperature		150	°C			

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 7$		-	5	32	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>		-	-	40	mA
V _T	on-state voltage	I _T = 32 A; T _j = 25 °C; <u>Fig. 10</u>		-	1.2	1.5	V
Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T_j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit		1000	-	-	V/µs

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		. 51.,
2	А	anode		A 🕌 K G
3	G	gate		sym037
mb	n.c.	mounting base; isolated	1 2 3 IITO-220	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
TYN20Y-600T	IITO220	TYN20Y-600TQ	Tube	50	IITO220E	15-Dec-2017

7. Marking

Table 4. Marking codes

Type number	Marking codes
TYN20Y-600T	TYN20Y 600T

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		600	V
V_{RRM}	repetitive peak reverse voltage		600	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 116 °C	12.7	А
$I_{T(RMS)}$	RMS on-state current	half sine wave; T _{mb} ≤ 116 °C; Fig. 1; Fig. 2; Fig. 3	20	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	230	А
		half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 8.3 \text{ ms}$	253	А
l ² t	I ² t for fusing	t _p = 10 ms; sine wave	265	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 70 mA	150	A/µs
I _{GM}	peak gate current		5	А
V_{RGM}	peak reverse gate voltage		5	V
P_GM	peak gate power		20	W
$P_{G(AV)}$	average gate power	over any 20 ms period	1	W
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		150	°C

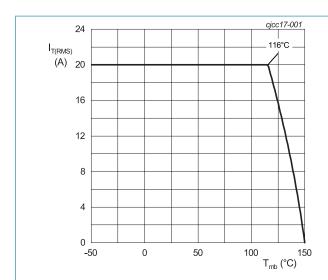
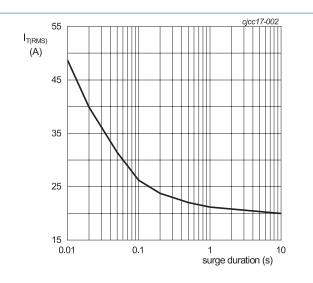


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values

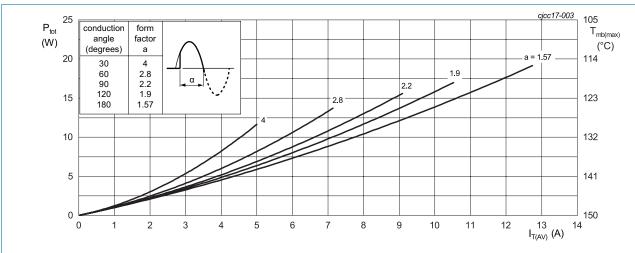


f = 50 Hz; T_{mb} = 116 °C

Fig. 2. RMS on-state current as a function of surge duration; maximum values

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 α = conduction angle

a = form factor = $I_{T(RMS)}$ / $I_{T(AV)}$

Fig. 3. Total power dissipation as a function of average on-state current; maximum values

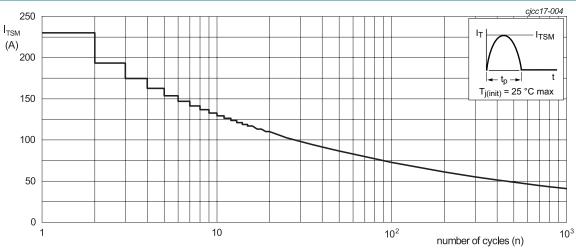
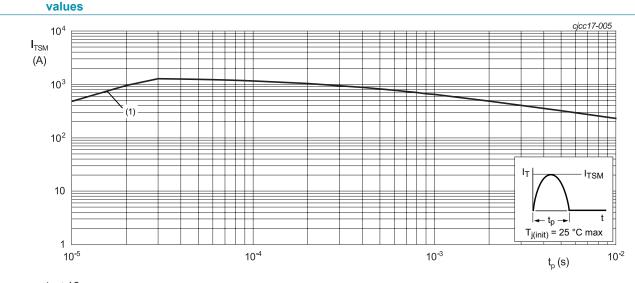


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum



 $t_p \le 10 \text{ ms}$; (1) $dI_T/dt \text{ limit}$

TYN20Y-600T

Fig. 5. Non-repetitive peak on-state current as a function of pulse width; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 6	-	-	1.8	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

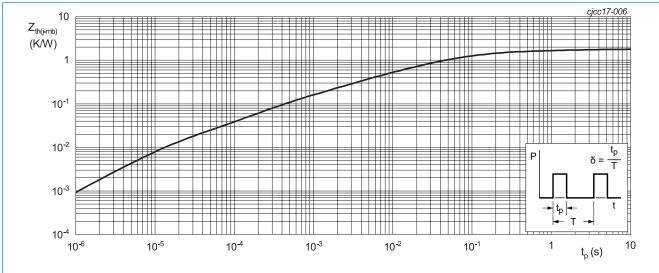


Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Isolation characteristics

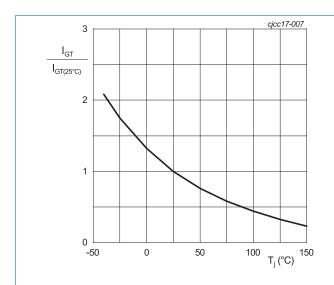
Table 7. Isolation characteristics

Symb	ol Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS}	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C_{isol}	isolation capacitance	from cathode to external heatsink	-	10	-	pF

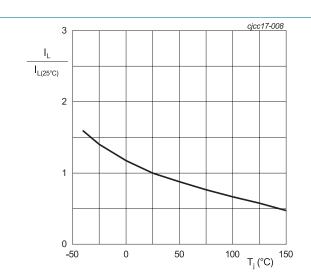
11. Characteristics

Table 8 Characteristics

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 7$	-	5	32	mA
I _L	latching current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C}; Fig. 8$	-	-	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V _T	on-state voltage	I _T = 32 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V _{GT} gate trigger voltage		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		$V_D = 400 \text{ V; } I_T = 0.1 \text{ A; } T_j = 150 ^{\circ}\text{C}$	0.2	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 150 °C	-	-	1	mA
I _R	reverse current	V _D = 600 V; T _j = 150 °C	-	-	1	mA
Dynamic c	haracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T_j = 150 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit	1000	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 20 \text{ A}; V_D = 600 \text{ V}; I_G = 100 \text{ mA};$ $(dI_G/dt)_M = 5 \text{ A}/\mu\text{s}; T_j = 25 ^{\circ}\text{C}$		2	-	μs
t _q	commutated turn-off time	$V_{DM} = 402 \text{ V; } T_j = 150 \text{ °C; } I_{TM} = 20 \text{ A; } V_R = 25 \text{ V; } dV_D/dt = 50 \text{ V/}\mu\text{s; } (dI_T/dt)_M = 30 \text{ A/}\mu\text{s; } R_{GK(ext)} = 100 \Omega\text{ ; } (V_{DM} = 67\% \text{ of } V_{DRM})$		70	-	μs







junction temperature

SCR

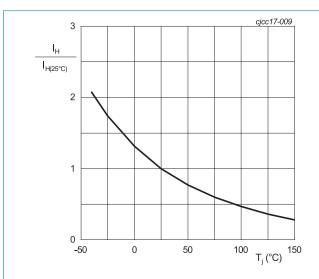
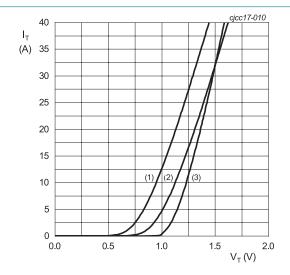


Fig. 9. Normalized holding current as a function of junction temperature



 $V_o = 0.969 \text{ V}; R_s = 0.0170 \Omega$

(1) $T_j = 150$ °C; typical values (2) $T_j = 150$ °C; maximum values

(3) $T_i = 25$ °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

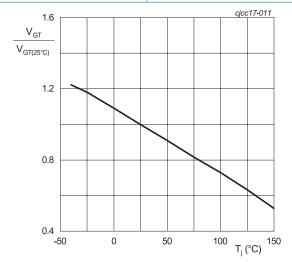
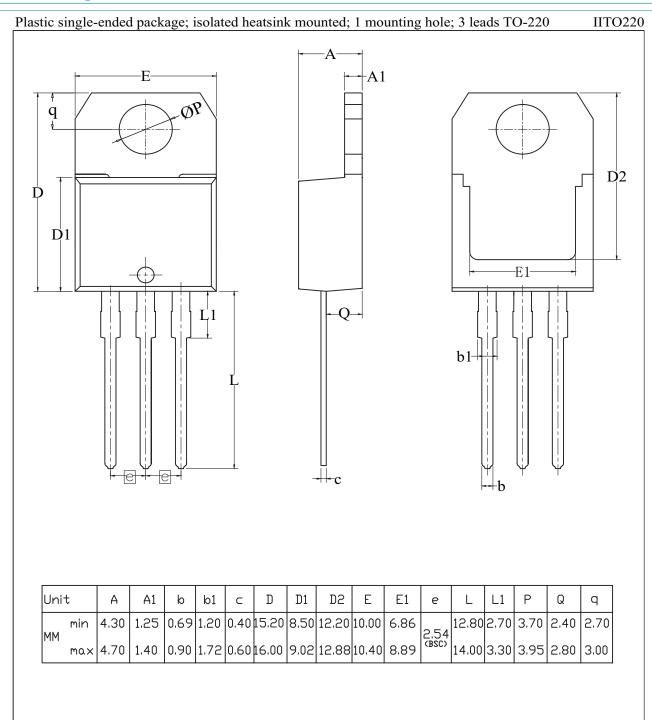


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

12. Package outline



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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